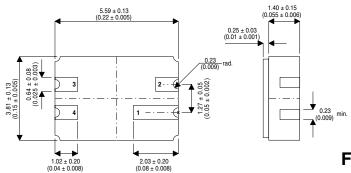


2N6660CSM4

MECHANICAL DATA

Dimensions in mm (inches)



N-CHANNEL ENHANCEMENT MODE MOSFET

 V_{DSS} 60V I_{D} 1.0A $R_{DS(op)}$ 3.0 Ω

LCC3 PACKAGE (MO-041BA)

(Underside View)

PAD 1 – DRAIN PAD 3 – SOURCE PAD 2 – N/C PAD 4 – GATE

FEATURES

- Faster switching
- Low Ciss
- Integral Source-Drain Diode
- High Input Impedance and High Gain

DESCRIPTION

This enhancement-mode (normally-off) vertical DMOS FET is ideally suited to a wide range of switching and amplifying applications where high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

Hi-Reliability Military and Space screening options available

ABSOLUTE MAXIMUM RATINGS $T_{CASE} = 25^{\circ}C$ unless otherwise stated

| V _{DS} | Drain - Source Voltage | 60V | | |
|------------------------|--|---------------|--|--|
| I _D | Drain Current - Continuous ($T_c = 25^{\circ}C$) | 1.0A | | |
| I _{DM} | Drain Current - Pulsed (Note 1) | 3A | | |
| $V_{\sf GS}$ | Gate - Source Voltage | ±20V | | |
| $P_{tot(1)}$ | Total Power Dissipation at T mounting base ≤ 25°C | 3.0W | | |
| | De-rate Linearly above 25°C | 0.020W/°C | | |
| $P_{tot(2)}$ | Total Power Dissipation at T _{ambient} ≤ 25°C | 0.5W | | |
| T_{j}, T_{stg} | Operating and Storage Junction Temperature Range | -55 to +175°C | | |

THERMAL DATA

| R_{thj-mb} | Thermal Resistance Junction – Mounting base | Max | 50 | °C/W |
|--------------|---|-----|----|------|
|--------------|---|-----|----|------|

NOTES:

- 1) Repetitive Rating: Pulse Width limited by maximum junction temperature.
- 2) Pulse Test: Pulse Width ≤ 300μS, Duty Cycle, δ 2%

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STATIC ELECTRICAL RATINGS (T_{case}=25°C unless otherwise stated)

| | Parameter | Test Cond | Min. | Тур. | Max. | Unit | |
|----------------------|---------------------------------------|-----------------------|------------------------|------|------|------|-----|
| V _{(BR)DSS} | Drain – Source Breakdown Voltage | $V_{GS} = 0V$ | $I_D = 10\mu A$ | 60 | - | - | |
| | | $V_{DS} = V_{GS}$ | I _D = 1.0mA | 0.8 | - | 2 | V |
| $V_{\rm GS(th)}$ | Gate – Source threshold Voltage | | T _c = 125°C | 0.3 | - | - | |
| | | | T _c = -55°C | - | - | 2.5 | |
| I _{GSS} | Gate – Source Leakage Current | $V_{GS} = \pm 20V$ | $V_{DS} = 0V$ | - | - | ±100 | nA |
| | | | T _c = 125°C | - | - | ±500 | IIA |
| | Zero Gate Voltage Drain Current | $V_{DS} = 48V$ | $V_{GS} = 0V$ | - | - | 1.0 | ^ |
| I _{DSS} | Zero Gate Voltage Drain Gurrent | | T _c = 125°C | - | - | 100 | μΑ |
| I _{D(on)} | On – State Drain Current (Note 2) | V _{DS} = 10V | $V_{GS} = 10V$ | 1.5 | - | - | Α |
| | | $V_{GS} = 5V$ | I _D = 0.3A | - | - | 5 | |
| R _{DS(on)} | Drain - Source On Resistance (Note 2) | V _{GS} = 10V | I _D = 1.0A | - | - | 3 | Ω |
| | | | T _c = 125°C | - | - | 5.6 | |
| g _{FS} | Forward Transconductance (Note 2) | V _{DS} = 25V | I _D = 0.5A | 170 | - | - | ms |
| V _{SD} | Diode Forward Voltage (Note 2) | $V_{GS} = 0V$ | I _s = 1.0A | 0.7 | - | 1.6 | V |
| t _{rr} | Body Diode Reverse Recovery | $V_{GS} = 0V$ | I _s = 1.0A | - | 350 | - | ns |

DYNAMIC CHARACTERISTICS

| C _{iss} | Input Capacitance | V _{DS} = 25V f = 1.0MHz V _{GS} = | | - | - | 50 | pF |
|------------------|------------------------------|---|--|---|---|----|----|
| C _{oss} | Output Capacitance | | $V_{GS} = 0V$ | | - | 40 | |
| C _{rss} | Reverse Transfer Capacitance | | | | - | 10 | |
| $T_{d(on)}$ | Turn-On Delay | $V_{DD} = 25V$ $R_{GS} = 50\Omega$ | $I_{DD} = 25V$ $I_{D} = 1.0A$ $R_{GS} = 50\Omega$ (Note 3) | • | ı | 10 | 20 |
| $T_{d(off)}$ | Turn-Off Delay Time | | | - | - | 10 | ns |

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